

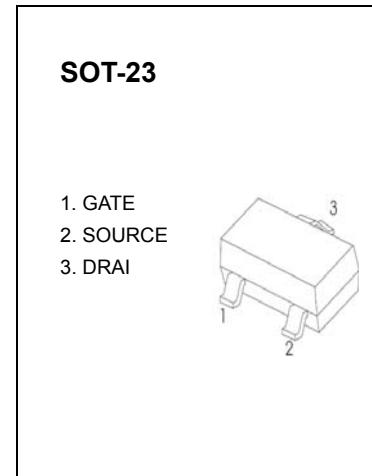
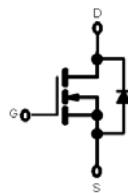
## SOT-23 Plastic-Encapsulate MOSFETS

**BSS138**

N-Channel 50-V(D-S) MOSFET

### FEATURE

- Low On-Resistance
- Low Gate Threshold Voltage
- Fast Switching Speed
- Low Input / Output Leakage



**Maximum ratings ( $T_a=25^\circ\text{C}$  unless otherwise noted)**

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	50	V
Continuous Gate-Source Voltage	$V_{GSS}$	$\pm 12$	
Continuous Drain Current	$I_D$	0.34	A
Power Dissipation	$P_D$	0.35	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	357	°C/W
Operating Temperature	$T_j$	150	°C
Storage Temperature	$T_{stg}$	-55 ~ +150	

**Electrical characteristics ( $T_a=25^\circ\text{C}$  unless otherwise noted)**

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
<b>Off characteristics</b>						
Drain-source breakdown voltage	$V_{(\text{BR})\text{DSS}}$	$V_{GS} = 0V, I_D = 250\mu\text{A}$	50			V
Gate-body leakage	$I_{GSS}$	$V_{DS} = 0V, V_{GS} = \pm 12V$			$\pm 1$	$\mu\text{A}$
		$V_{DS} = 0V, V_{GS} = \pm 10V$			$\pm 0.5$	$\mu\text{A}$
		$V_{DS} = 0V, V_{GS} = \pm 5V$			$\pm 0.05$	$\mu\text{A}$
Zero gate voltage drain current	$I_{DSS}$	$V_{DS} = 50V, V_{GS} = 0V$			0.1	$\mu\text{A}$
<b>On characteristics</b>						
Gate-threshold voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = 0.25\text{mA}$	0.1		0.2	A
Static drain-source on-resistance	$R_{DS(\text{on})}$	$V_{GS} = 1.8V, I_D = 0.05\text{A}$				
		$V_{GS} = 2.5V, I_D = 0.05\text{A}$			1.20	3.0
		$V_{GS} = 5V, I_D = 0.05\text{A}$				1.6
Forward transconductance	$g_{FS}$	$V_{DS} = 10V, I_D = 0.2\text{A}$	0.20			S
<b>Dynamic characteristics*</b>						
Input capacitance	$C_{iss}$	$V_{DS} = 25V, V_{GS} = 0V, f = 1\text{MHz}$		58		pF
Output capacitance	$C_{oss}$			9.75		
Reverse transfer capacitance	$C_{rss}$			5.2		
Gate resistance	$R_G$	$V_{DS} = 5V, V_{GS} = 10\text{mV}, f = 1\text{MHz}$		281		$\Omega$
<b>Switching characteristics*</b>						
Turn-on delay time	$t_{d(on)}$	$V_{DD} = 30V, V_{DS} = 10V, I_D = 0.29A, R_{GEN} = 6\Omega$			5	ns
Rise time	$t_r$				5	
Turn-off delay time	$t_{d(off)}$				60	
Fall time	$t_f$				35	
<b>Drain-source body diode characteristics</b>						
Body diode forward voltage	$V_{SD}$	$I_S = 0.115A, V_{GS} = 0V$			1.2	V

\* These parameters have no way to verify.